

NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE0117K uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

General Features

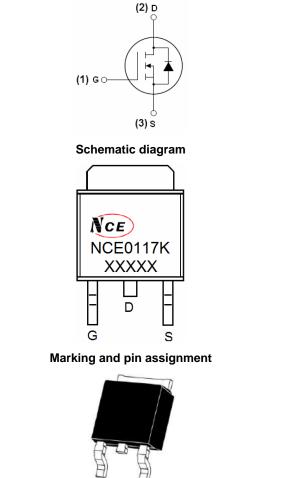
- $V_{DS} = 100V, I_D = 17A$ $R_{DS(ON)} < 70m\Omega @ V_{GS} = 10V$ (Typ:56m Ω) $R_{DS(ON)} < 85m\Omega @ V_{GS} = 4.5V$ (Typ:65m Ω)
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

Application

- Power switching application
- Hard switched and high frequency circuits

100% UIS TESTED!

100% ΔVds TESTED!



TO-252-2L top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE0117K	NCE0117K	TO-252-2L	-	-	-

Absolute Maximum Ratings (T_c=25[°]Cunless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	VDS	100	V	
Gate-Source Voltage	Vgs	±20	V	
Drain Current-Continuous	I _D	17	A	
Drain Current-Continuous(T _C =100°C)	I _D (100℃)	12	A	
Pulsed Drain Current	I _{DM}	60	Α	
Maximum Power Dissipation	PD	55	W	
Single pulse avalanche energy (Note 5)	E _{AS}	28	mJ	
Operating Junction and Storage Temperature Range	TJ,TSTG	-55 To 150	°C	



Thermal Characteristic

Thermal Resistance, Junction-to-Case ^(Note 2)	$R_{ extsf{ heta}JC}$	2.27	°C/W
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Electrical Characteristics (T_c=25[°]C unless otherwise noted)

Symbol	Condition	Min	Тур	Max	Unit	
BV _{DSS}	V _{GS} =0V I _D =250µA	100	110	-	V	
I _{DSS}	V _{DS} =100V,V _{GS} =0V	-	-	1	μA	
I _{GSS}	I _{GSS} V _{GS} =±20V,V _{DS} =0V		-	±100	nA	
V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250µA	1.2	1.8	2.5	V	
	V _{GS} =10V, I _D =5A	-	56	70	mΩ	
RDS(ON)	V _{GS} =4.5V, I _D =3A		65	85		
g _{FS}	V _{DS} =5V,I _D =5A	12	-	-	S	
C _{lss}		-	1350	-	PF	
C _{oss}		-	240	-	PF	
C _{rss}	F=1.0WHZ	-	180	-	PF	
		•				
t _{d(on)}		-	13.8	-	nS	
tr	V_{DD} =30V,RL=15 Ω	-	9.3	-	nS	
t _{d(off)}	V _{GS} =10V,R _G =2.5Ω	-	43.8	-	nS	
t _f		-	11.4	-	nS	
Qg)/ <u>20)//</u> 54	-	30		nC	
Q _{gs}		-	6.4	-	nC	
Q _{gd}	V _{GS} =10V	-	8.6	-	nC	
					•	
V _{SD}	V _{GS} =0V,I _S =17A	-	-	1.2	V	
I _S		-	-	17	Α	
t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD				v LS+LD)	
	BVDSS IDSS IDSS IGSS VGS(th) RDS(ON) GFS Cliss Cliss Cliss Criss Criss Cliss Qriss Criss Qg Qg Qg Qg Qgd VSD Is	$ \begin{array}{ c c c c c } \hline & & & & & & & & & \\ \hline & & & & & & & &$	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{ c c c c c c } \hline BV_{DSS} & V_{GS} = 0V \ l_{D} = 250 \mu A & 100 & 110 \\ \hline l_{DSS} & V_{DS} = 100V, V_{GS} = 0V & - & - \\ \hline l_{GSS} & V_{GS} = \pm 20V, V_{DS} = 0V & - & - \\ \hline V_{GS(th)} & V_{DS} = V_{GS}, \ l_{D} = 250 \mu A & 1.2 & 1.8 \\ \hline V_{GS}(0N) & V_{DS} = V_{GS}, \ l_{D} = 5A & - & 56 \\ \hline V_{GS} = 4.5V, \ l_{D} = 3A & 65 \\ \hline g_{FS} & V_{DS} = 5V, \ l_{D} = 5A & 12 & - \\ \hline \hline C_{ISS} & V_{DS} = 5V, \ l_{D} = 5A & 12 & - \\ \hline \hline C_{ISS} & V_{DS} = 25V, \ V_{GS} = 0V, \\ \hline C_{rss} & V_{DS} = 25V, \ V_{GS} = 0V, \\ \hline \hline C_{rss} & V_{DS} = 25V, \ V_{GS} = 0V, \\ \hline \hline & 1380 & - & 180 \\ \hline \hline \hline \\ \hline \hline t_{d(off)} & V_{GS} = 10V, \ R_{G} = 2.5\Omega & - & 43.8 \\ \hline t_{f} & V_{DS} = 30V, \ l_{D} = 5A, \\ \hline V_{GS} = 10V & - & 8.6 \\ \hline \hline \hline \\ \hline \hline V_{SD} & V_{GS} = 0V, \ l_{S} = 17A & - & - \\ \hline \hline \\ \hline V_{SD} & V_{GS} = 0V, \ l_{S} = 17A & - & - \\ \hline \hline \end{array}$	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, $t \le 10$ sec.

3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

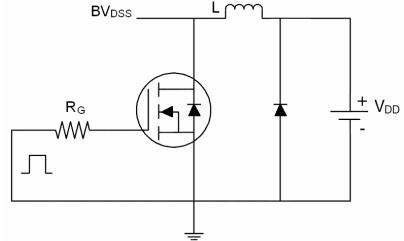
4. Guaranteed by design, not subject to production

5. EAS condition : Tj=25 $^\circ\!\mathrm{C}$,V_DD=50V,V_G=10V,L=0.5mH,Rg=25 Ω

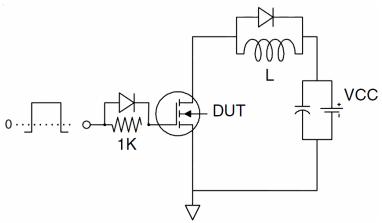


Test Circuit

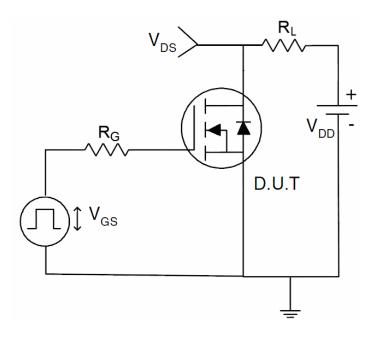
1) E_{AS} test Circuit



2) Gate charge test Circuit



3) Switch Time Test Circuit





V_{GS}=4.5V I_D=3A

125 150

20

25° С

0.8

1.0

0.6

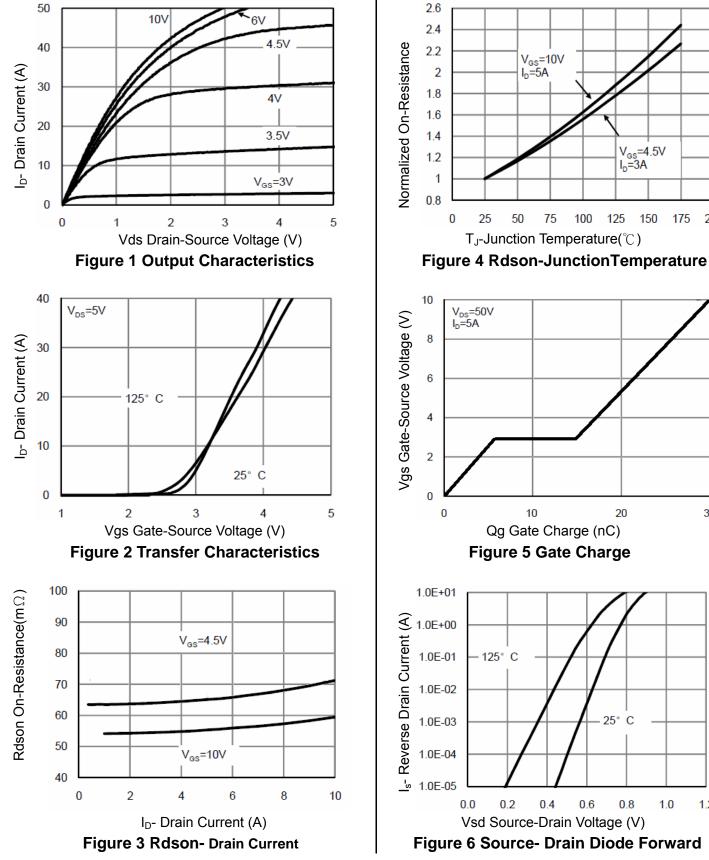
175

200

30

100





1.2

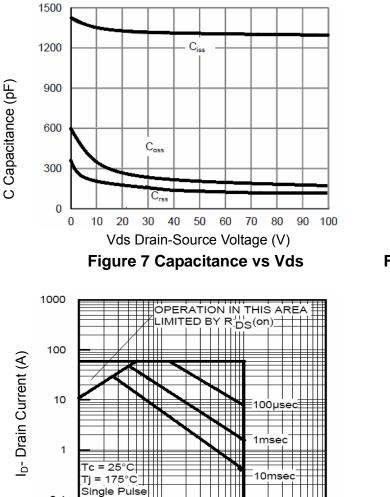


0.1

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http://www.ncepower.com



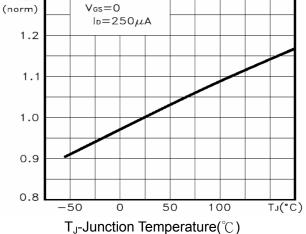


10

Vds Drain-Source Voltage (V)

Figure 8 Safe Operation Area

100



BV_{DSS}

Figure 9 BV_{DSS} vs Junction Temperature

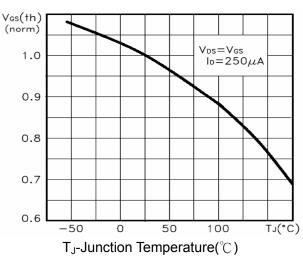
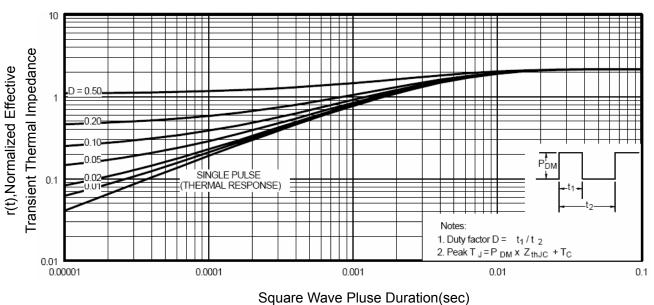


Figure 10 V_{GS(th)} vs Junction Temperature

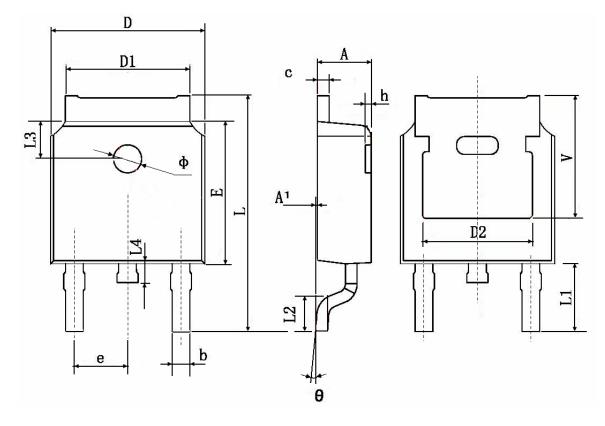


1000

Figure 11 Normalized Maximum Transient Thermal Impedance



TO-252 Package Information



Cumb ol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
с	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	4.83	0 TYP.	0.190 TYP.		
E	6.000	6.200	0.236	0.244	
e	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900	TYP.	0.114 TYP.		
L2	1.400	1.700	0.055	0.067	
L3	1.600 TYP.		0.063 TYP.		
L4	0.600	1.000	0.024	0.039	
Φ	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.350) TYP.	0.211 TYP.		



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